NSN 5961-01-159-3337

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-159-3337 **Inclosure Material:** Metal **Overall Length:** 0.225 inches **Overall Diameter:** 0.358 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 collector to emitter voltage, dc with base short-circuited to emitter and 30.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 05896-723084 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**